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PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10046741	FILING DATE 01/17/2002	CLASS 438	SUBCLASS 479	GAU 2812	EXAMINER Mu/puri
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**CONTINUING DATA VERIFIED: *W. Ono*

** FOREIGN APPLICATIONS VERIFIED:

JAPAN 2001-009144 01/17/2001

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	
Foreign priority claimed 35 USC 119 conditions met Verified and Acknowledged Examiner's initials		<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> yes <input checked="" type="checkbox"/> no <i>S. M.</i>	ATTORNEY DOCKET NO 3885-0103P
TITLE : Method for fabricating III-V compound semiconductor			

U.S. DEPT. OF COMM /PAT. & TM-PTO-436L(Rev. 12-94)

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Assistant Examiner	
ISSUE FEE		DRAWING	
Amount Due	Date Paid	Total Claims	Print Claim for O.G
		Sheets Drwg. Figs.Drwg. Print Fig.	
		Primary Examiner	
		PREPARED FOR ISSUE	
		Application Examiner	
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